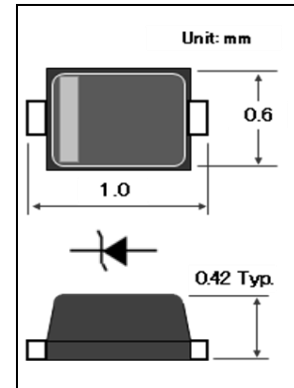


Schottky Barrier Diode

- ◇ Low current rectification
- ◇ Low forward voltage
- ◇ SOD923 Micro SMD package (Fig-1)
Dimensions: 1.0 mm x 0.6 mm (0.039" x 0.024")
- ◇ RoHS compliant
- ◇ UL-94 V-0 / Green EMC
- ◇ Matte Tin Lead finish (Pb-Free)
- ◇ Cathode Band / Device marking:

Device Marking Code	
RB521CS-30	F



Mark: refer to Device Marking

Absolute Maximum Ratings (Ta = 25 °C)

Symbol	Parameter	Value	Units
V_{RRM}	Repetitive Peak Reverse Voltage	30	V
V_R	Reverse Voltage	30	V
I_O	Continuous Forward Current	100	mA
I_{FSM}	Non-Repetitive Peak Forward Current *1	500	mA
T_J	Junction Temperature	125	°C
T_{STG}	Storage Temperature	-55 to +125	°C

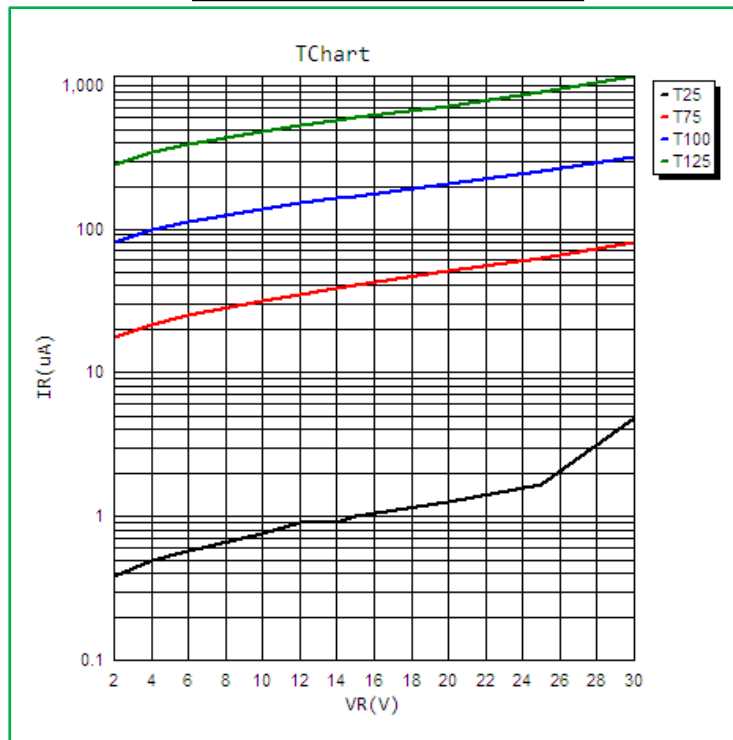
*1: 8.3ms Single Half Sine-Wave

Electrical Characteristics (Ta = 25 °C)

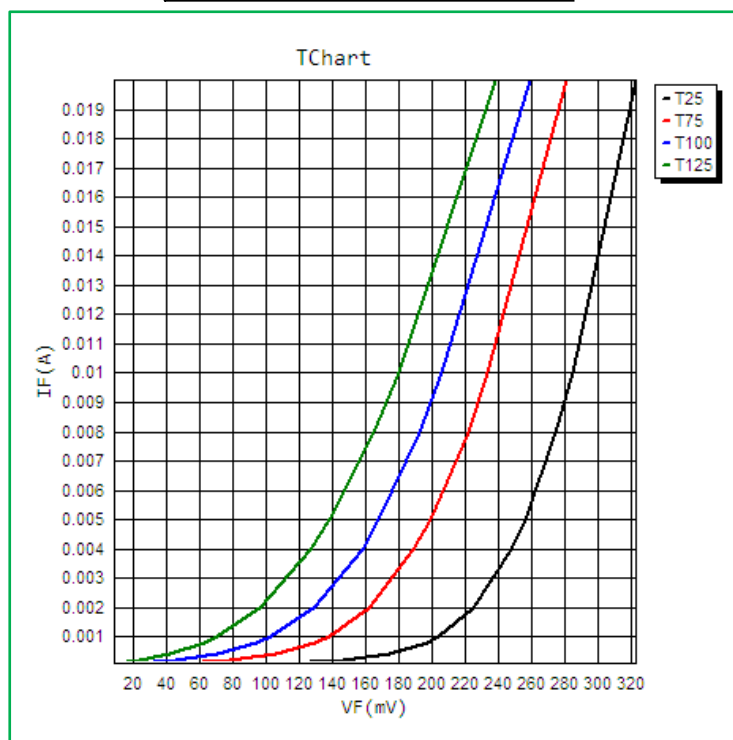
Symbol	Parameter	Conditions	Min	TYP	Max	Units
V_F	Forward Voltage	$I_F = 10\text{mA}$			0.35	V
		$I_F = 20\text{mA}$			0.40	V
BV_R	Breakdown Voltage	$I_R = 100\ \mu\text{A}$	30			V
I_R	Reverse Current	$V_R = 10\text{V}$			10	μA
		$V_R = 30\text{V}$			50	μA

Typical Characteristics

Forward Characteristics



Reverse Characteristics



Ordering Information

Device	Package	Shipping	Tape wide	Embos pitch	Tape specification	Notes
RB521CS-30	SOD923	8,000 pcs / 7" Reel	8 mm	2 mm	Conductive	

Package Dimensions

